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Photocatlytic Performance of TiO₂ Films on Carbon Felt Prepared by Sputtering Deposition

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In recent years, TiO_2 is one of the suitable materials in the electrical, catalysis and solar cell and environmental application. Many processing methods such as sol-gel, plasma spray, CVD and PVD can be used to prepare TiO_2 materials in powder or thin film type. Sputtering processes have favorable features such as lower process temperature, good adhesion, good uniformity and easy modification on the film properties. When anatase TiO_2 is irradiated with UV right that is great than the gand gap energy of the catalyst (E_g is 3.2 eV), then photocatalytic reactions occur.

In this work, TiO_2 films on carbon felt were deposited at different $Ar:O_2$ flow rations by dc reactive magnetron sputtering. The influences of $Ar:O_2$ flow ratio on the microstructure and photocatalytic activies of TiO_2 films on carbon felt were investigated. The films were characterized using XRD, SEM, and UV-vis-NIR spectrophotometer. Photocatalytic activities of the samples were evaluated by the degradation of Perchlorate ions (ClO₄⁻) under UV irradiation.